



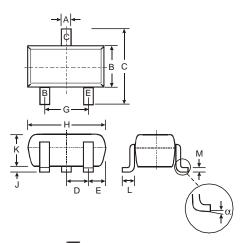
MMSTA13/MMSTA14

Features

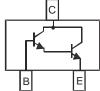
- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (MMSTA63/MMSTA64)
- Ideal for Low Power Amplification and Switching
- High Current Gain
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA13 Marking K2D, K3D, See Page 3
- MMSTA14 Marking K3D, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323										
Dim	Min	Max								
Α	0.25	0.40								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 N	ominal								
Е	0.30	0.40								
G	1.20	1.40								
Н	1.80	2.20								
J	0.0	0.10								
K	0.90	1.00								
L	0.25	0.40								
М	0.10	0.18								
α	0°	8°								
All Din	nensions	in mm								



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	10	V
Collector Current - Continuous (Note 1)	Ic	300	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

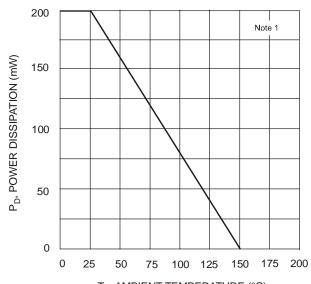
Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)		•			•	•
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	30		V	$I_C = 100 \mu A V_{BE} = 0 V$
Collector Cutoff Current		I _{CBO}	_	100	nA	$V_{CB} = 30V, I_{E} = 0$
Emitter Cutoff Current		I _{EBO}	_	100	nA	$V_{EB} = 10V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)						
DC Current Gain	MMSTA13 MMSTA14 MMSTA13 MMSTA14	h _{FE}	5,000 10,000 10,000 20,000	_	_	$\begin{split} & I_{C} = \ 10 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ & I_{C} = \ 10 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ & I_{C} = 100 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ & I_{C} = 100 \text{mA}, \ V_{CE} = 5.0 \text{V} \end{split}$
Collector-Emitter Saturation Voltage		V _{CE(SAT)}		1.5	V	$I_C = 100 \text{mA}, I_B = 100 \mu \text{A}$
Base-Emitter Saturation Voltage		$V_{BE(SAT)}$		2.0	V	$I_C = 100 \text{mA}, V_{CE} = 5.0 \text{V}$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	8.0 Typical		pF	$V_{CB} = 10V, f = 1.0MHz, I_{E} = 0$	
Input Capacitance		C _{ibo}	15 Typical		pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Current Gain-Bandwidth Product		f _T	125		MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz

Note: 5. Short duration pulse test used to minimize self-heating effect.



T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs. Ambient Temperature

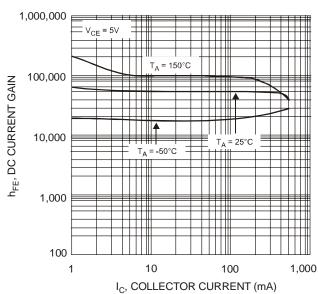


Fig. 3, DC Current Gain vs. Collector Current

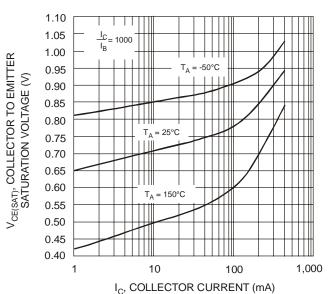


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

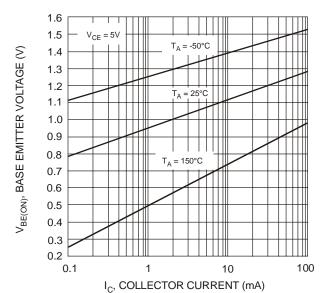
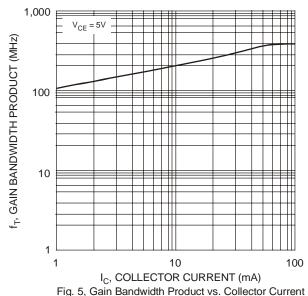


Fig. 4, Base Emitter Voltage vs. Collector Current



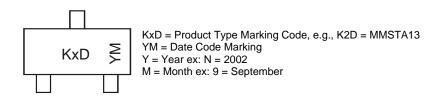


Ordering Information (Note 4 & 6)

Device	Packaging	Shipping		
MMSTA13-7-F	SOT-323	3000/Tape & Reel		
MMSTA14-7-F	SOT-323	3000/Tape & Reel		

6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information



Date Code Key

Year	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	L	М	N	Р	R	S	Т	J	V	W	Χ	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

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FJB102TM BCV26E6327HTSA1 BCV46E6327HTSA1 BSP61H6327XTSA1 BU941ZPFI 2SB1316TL 2SD1980TL NTE2350 NTE245

NTE246 NTE2649